

# Yu Kobayashi

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/1583380/publications.pdf>

Version: 2024-02-01

15  
papers

916  
citations

840776

11  
h-index

1125743

13  
g-index

15  
all docs

15  
docs citations

15  
times ranked

1764  
citing authors

#	ARTICLE	IF	CITATIONS
1	Room-Temperature Chiral Light-Emitting Diode Based on Strained Monolayer Semiconductors. <i>Advanced Materials</i> , 2021, 33, e2100601.	21.0	16
2	Room-Temperature Chiral Light-Emitting Diode Based on Strained Monolayer Semiconductors (Adv.) <i>TJ ETQq0 0,0 rgBT /Overlock 10</i>	21.0	0
3	High-Resolution Electrochemical Mapping of the Hydrogen Evolution Reaction on Transition-Metal Dichalcogenide Nanosheets. <i>Angewandte Chemie</i> , 2020, 132, 3629-3636.	2.0	11
4	High-Resolution Electrochemical Mapping of the Hydrogen Evolution Reaction on Transition-Metal Dichalcogenide Nanosheets. <i>Angewandte Chemie - International Edition</i> , 2020, 59, 3601-3608.	13.8	136
5	One-dimensional van der Waals heterostructures. <i>Science</i> , 2020, 367, 537-542.	12.6	238
6	Exciton Polarization and Renormalization Effect for Optical Modulation in Monolayer Semiconductors. <i>ACS Nano</i> , 2019, 13, 9218-9226.	14.6	9
7	Growth and characterization of in-plane heterostructures based on two-dimensional materials. , 2019, , .		0
8	Tunable Chemical Coupling in Two-Dimensional van der Waals Electrostatic Heterostructures. <i>ACS Nano</i> , 2019, 13, 11214-11223.	14.6	13
9	Restoring the intrinsic optical properties of CVD-grown MoS <sub>2</sub> monolayers and their heterostructures. <i>Nanoscale</i> , 2019, 11, 12798-12803.	5.6	37
10	Continuous Heteroepitaxy of Two-Dimensional Heterostructures Based on Layered Chalcogenides. <i>ACS Nano</i> , 2019, 13, 7527-7535.	14.6	48
11	Direct and Indirect Interlayer Excitons in a van der Waals Heterostructure of hBN/WS <sub>2</sub> /MoS <sub>2</sub> /hBN. <i>ACS Nano</i> , 2018, 12, 2498-2505.	14.6	96
12	Modulation of electrical potential and conductivity in an atomic-layer semiconductor heterojunction. <i>Scientific Reports</i> , 2016, 6, 31223.	3.3	44
13	Microscopic basis for the band engineering of Mo <sub>1-x</sub> W <sub>x</sub> S <sub>2</sub> -based heterojunction. <i>Scientific Reports</i> , 2015, 5, 14808.	3.3	52
14	Bandgap-tunable lateral and vertical heterostructures based on monolayer Mo <sub>1-x</sub> W <sub>x</sub> S <sub>2</sub> alloys. <i>Nano Research</i> , 2015, 8, 3261-3271.	10.4	54
15	Growth and Optical Properties of High-Quality Monolayer WS <sub>2</sub> on Graphite. <i>ACS Nano</i> , 2015, 9, 4056-4063.	14.6	162